## NSN 5961-00-456-3400

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-456-3400 **Inclosure Material:** Metal **Overall Length:** 0.214 inches **Overall Diameter:** 0.121 inches **Mounting Method:** Press fit **Features Provided:** Gold plated leads and hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 0.4 forward voltage, dc and 1.0 forward voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule **Specification Data:** 96214-590528-2 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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